



ELECTRONICS, INC.
 44 FARRAND STREET
 BLOOMFIELD, NJ 07003
 (973) 748-5089
<http://www.nteinc.com>

NTE4021B & NTE4021BT Integrated Circuit CMOS, 8-Bit Static Shift Register

Description:

The NTE4021B (16-Lead DIP) and NTE4021BT (SOIC-16) are 8-bit static shift registers constructed with MOS P-Channel and N-Channel enhancement mode devices in a single monolithic structure. These devices find primary use in parallel-to-serial data conversion, asynchronous parallel input, serial output data queueing; and other general purpose register applications requiring low power and/or high noise immunity.

Features:

- Asynchronous Parallel Input/Serial Output
- Synchronous Serial Output/Serial Output
- Full Static Operation
- “Q” Outputs from Sixth, Seventh, and Eighth Stages
- Double Diode Input Protection
- Supply Voltage Range: 3Vdc to 18Vdc
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load Over the Rated Temperature Range

Absolute Maximum Ratings: (Voltages referenced to V_{SS} , Note 1)

DC Supply Voltage, V_{DD}	-0.5 to +18.0V
Input Voltage (DC or Transient), V_{in}	-0.5 to V_{DD} to +0.5V
Output Voltage (DC or Transient), V_{out}	-0.5 to V_{DD} to +0.5V
Input Current (DC or Transient, Per Pin), I_{in}	± 10 mA
Output Current (DC or Transient, Per Pin), I_{out}	± 10 mA
Power Dissipation (Per Package), P_D	500mW
Temperature Derating (from +65° to +125°C)	-7.0mW/°C
Storage Temperature, T_{stg}	-65° to +150°C
Lead Temperature (During Soldering, 8sec max), T_L	+260°C

Note 1. Maximum Ratings are those values beyond which damage to the device may occur.

Electrical Characteristics: (Voltages referenced to V_{SS} , Note 2)

Parameter	Symbol	V_{DD} Vdc	-55°C		+25°C			+125°C		Unit	
			Min	Max	Min	Typ	Max	Min	Max		
Output Voltage "0" Level $V_{in} = V_{DD}$ or 0	V_{OL}	5.0	-	0.05	-	0	0.05	-	0.05	Vdc	
		10	-	0.05	-	0	0.05	-	0.05	Vdc	
		15	-	0.05	-	0	0.05	-	0.05	Vdc	
	"1" Level $V_{in} = 0$ or V_{DD}	V_{OH}	5.0	4.95	-	4.95	5.0	-	4.95	-	Vdc
			10	9.95	-	9.95	10	-	9.95	-	Vdc
			15	14.95	-	14.95	15	-	14.95	-	Vdc
Input Voltage "0" Level ($V_O = 4.5$ or 0.5 Vdc) ($V_O = 9.0$ or 1.0 Vdc) ($V_O = 13.5$ or 1.5 Vdc)	V_{IL}	5.0	-	1.5	-	2.25	1.5	-	1.5	Vdc	
		10	-	3.0	-	4.50	3.0	-	3.0	Vdc	
		15	-	4.0	-	6.75	4.0	-	4.0	Vdc	
	"1" Level ($V_O = 0.5$ or 4.5 Vdc) ($V_O = 1.0$ or 9.0 Vdc) ($V_O = 1.5$ or 13.5 Vdc)	V_{IH}	5.0	3.5	-	3.5	2.75	-	3.5	-	Vdc
			10	7.0	-	7.0	5.50	-	7.0	-	Vdc
			15	11.0	-	11.0	8.25	-	11.0	-	Vdc
Output Drive Current Source ($V_{OH} = 2.5$ Vdc) ($V_{OH} = 4.6$ Vdc) ($V_{OH} = 9.5$ Vdc) ($V_{OH} = 13.5$ Vdc)	I_{OH}	5.0	-3.0	-	-2.4	-4.2	-	-1.7	-	mAdc	
		5.0	-0.64	-	-0.51	-0.88	-	-0.36	-	mAdc	
		10	-1.6	-	-1.3	-2.25	-	-0.9	-	mAdc	
		15	-4.2	-	-3.4	-8.8	-	-2.4	-	mAdc	
	Sink ($V_{OL} = 0.4$ Vdc) ($V_{OL} = 0.5$ Vdc) ($V_{OL} = 1.5$ Vdc)	I_{OL}	5.0	0.64	-	0.51	0.88	-	0.36	-	mAdc
			10	1.6	-	1.3	2.25	-	0.9	-	mAdc
15			4.2	-	3.4	8.8	-	2.4	-	mAdc	
Input Current	I_{in}	15	-	± 0.1	-	± 0.00001	± 0.1	-	± 0.1	μ Adc	
Input Capacitance ($V_{IN} = 0$)	C_{in}	-	-	-	-	5.0	7.5	-	-	pF	
Quiescent Current (Per Package)	I_{DD}	5.0	-	5.0	-	0.005	5.0	-	150	μ Adc	
		10	-	10	-	0.010	10	-	300	μ Adc	
		15	-	15	-	0.015	15	-	600	μ Adc	
Total Supply Current (Dynamic plus Quiescent, Per Package, $C_L = 50$ pF on All Buffers Switching Note 3, Note 4)	I_T	5.0	$I_T = (0.75\mu A/kHz) f + I_{DD}$							μ Adc	
		10	$I_T = (1.5\mu A/kHz) f + I_{DD}$							μ Adc	
		15	$I_T = (2.25\mu A/kHz) f + I_{DD}$							μ Adc	

Note 2. Data labeled "Typ" is not to be used for design purposes but is intended as an indication of the device's potential performance.

Note 3. The formulas given are for the typical characteristics only at +25°C.

Note 4. To calculate total supply current at loads other than 50pF:

$$I_T(C_L) = I_T(50pF) + (C_L - 50) V_{fk}$$

where: I_T is in μA (per package), C_L in pF, $V = (V_{DD} - V_{SS})$ in volts, f in kHz is input frequency, and $k = 0.0015$.

Switching Characteristics: ($C_L = 50\text{pF}$, $T_A = +25^\circ\text{C}$, Note 2)

Parameter	Symbol	V_{DD} Vdc	Min	Typ	Max	Unit
Output Rise and Fall Time $t_{TLH}, t_{THL} = (1.5\text{ns/pf}) C_L + 25\text{ns}$ $t_{TLH}, t_{THL} = (0.75\text{ns/pf}) C_L + 12.5\text{ns}$ $t_{TLH}, t_{THL} = (0.55\text{ns/pf}) C_L + 9.5\text{ns}$	$t_{TLH},$ t_{THL}	5.0	–	100	200	ns
		10	–	50	100	ns
		15	–	40	80	ns
Propagation Delay Time (Clock to Q, P/S to Q) $t_{PHL}, t_{PLH} = (1.7\text{ns/pf}) C_L + 315\text{ns}$ $t_{PHL}, t_{PLH} = (0.66\text{ns/pf}) C_L + 137\text{ns}$ $t_{PHL}, t_{PLH} = (0.5\text{ns/pf}) C_L + 90\text{ns}$	$t_{PLH},$ t_{PHL}	5.0	–	400	800	ns
		10	–	170	340	ns
		15	–	115	230	ns
Clock Pulse Width	t_{WH}	5.0	400	150	–	ns
		10	175	75	–	ns
		15	135	40	–	ns
Clock Frequency	f_{cl}	5.0	–	3.0	1.5	MHz
		10	–	6.0	3.0	MHz
		15	–	8.0	4.0	MHz
Parallel/Serial Control Pulse Width	t_{WH}	5.0	400	150	–	ns
		10	175	75	–	ns
		15	135	40	–	ns
Setup Time, P/S to Clock	t_{su}	5.0	200	100	–	ns
		10	100	50	–	ns
		15	80	40	–	ns
Hold Time, P/S to Clock	t_h	5.0	20	–2.5	–	ns
		10	20	–10	–	ns
		15	25	0	–	ns
Setup Time, Data (Parallel or Serial) to Clock or P/S	t_{su}	5.0	350	150	–	ns
		10	80	50	–	ns
		15	60	30	–	ns
Hold Time, Clock to D_S	t_h	5.0	45	0	–	ns
		10	35	0	–	ns
		15	35	5	–	ns
Hold Time, Clock to P_n	t_h	5.0	50	25	–	ns
		10	45	20	–	ns
		15	45	20	–	ns
Input Clock Rise Time	$T_{r(cl)}$	5.0	–	–	15	ns
		10	–	–	5	ns
		15	–	–	4	ns

Note 2. Data labeled “Typ” is not to be used for design purposes but is intended as an indication of the device’s potential performance.

Note 3. The formulas given are for the typical characteristics only at $+25^\circ\text{C}$.

Truth Table:

Serial Operation

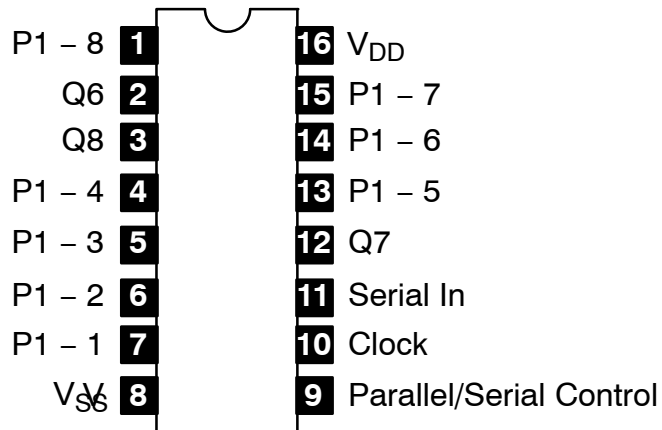
t	Clock	D _S	P/S	Q6 t = n+6	Q7 t = n+7	Q8 t = n+8
n		0	0	0	?	?
n+1		1	0	1	0	?
n+2		0	0	0	1	0
n+3		1	0	1	0	1
		X	0	Q6	Q7	Q8

Parallel Operation

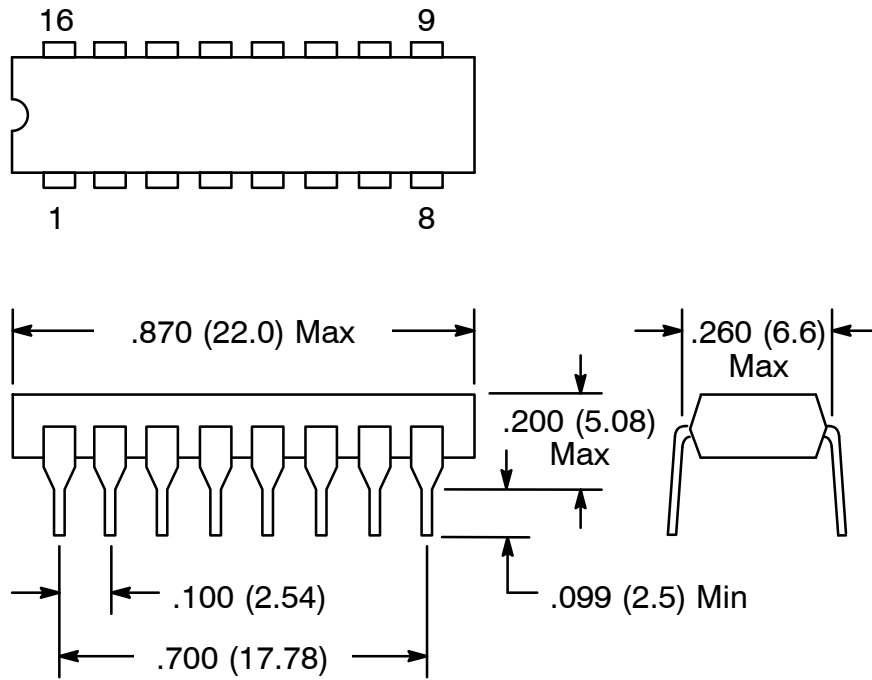
Clock	D _S	P/S	P _n	*Q _n
	X	X	0	0
	X	X	1	1

* = Q6, Q7, & Q8 are available externally
 X = Don't Care

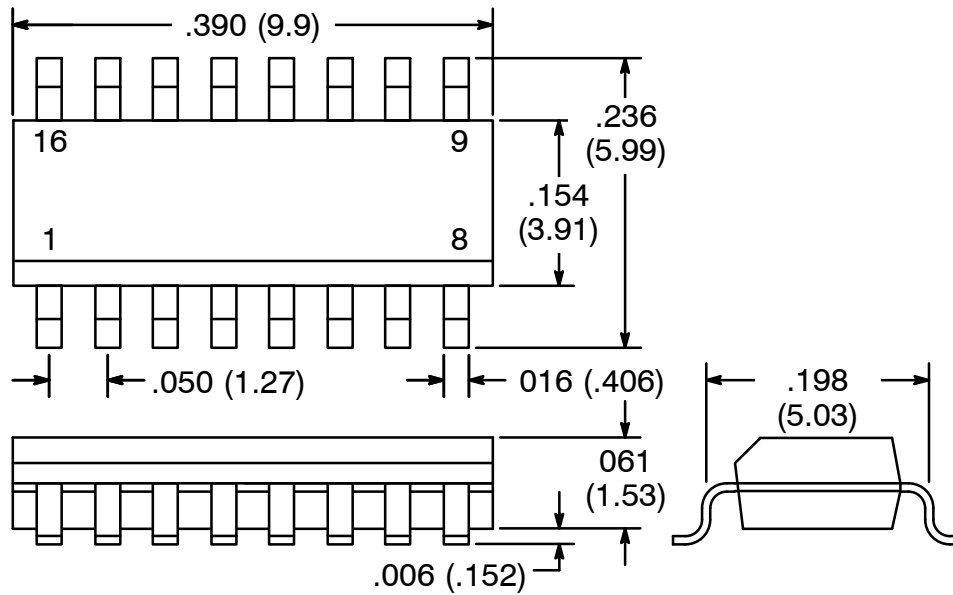
Pin Connection Diagram



NTE4021B



NTE4021BT



NOTE: Pin1 on Beveled Edge